

Low Capacitance Bidirectional TVS/ESD Protection Diode

DESCRIPTION

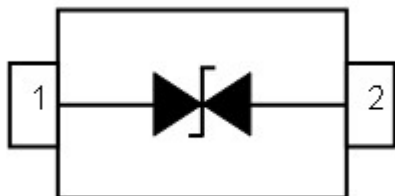
The SLPESD5V0S1BB is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its small size, it is suited for use in cellular phones, portable devices, digital cameras, power supplies and many other portable applications where board space comes at a premium. Also because of its low capacitance, it is suited for use in high frequency designs such as USB 2.0 high speed, VGA, DVI, SDI and other high speed line applications.

This device has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD(electrostatic discharge), and EFT (electrical fast transients).

ORDERING INFORMATION

- ✧ Device: SLPESD5V0S1BB
- ✧ Package: SOD-523
- ✧ Marking: 5C
- ✧ Material: Halogen free
- ✧ Packing: Tape & Reel
- ✧ Quantity per reel: 3,000pcs

PIN CONFIGURATION



FEATURES

- ✧ IEC61000-4-2 (ESD) $\pm 15\text{kV}$ (air), $\pm 8\text{kV}$ (contact)
- ✧ IEC61000-4-4 (EFT) 40A (5/50ns)
- ✧ Peak power dissipation: 80W (8/20 μs)
- ✧ Protects one directional I/O line
- ✧ Low clamping voltage
- ✧ Working voltages : 5V
- ✧ Low leakage current
- ✧ Low capacitance

MACHANICAL DATA

- ✧ SOD-523 package
- ✧ Terminals: Gold plated, solderable per MIL-STD-750, method 2026
- ✧ Packaging: Tape and Reel
- ✧ Reel size: 7 inch
- ✧ Weight: 0.001 gram (approx.)

APPLICATIONS

- ✧ High Speed Line :USB1.0/2.0, VGA, DVI, SDI,
- ✧ Serial and Parallel Ports
- ✧ Notebooks, Desktops, Servers
- ✧ Projection TV
- ✧ Cellular handsets and accessories
- ✧ Portable instrumentation
- ✧ Peripherals

PACKAGE OUTLINE

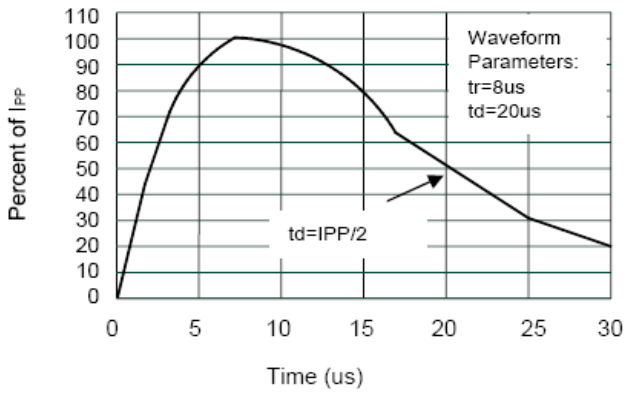
ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value	Units
V_{ESD}	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	± 15 ± 8	kV
P_{PP}	Peak Pulse Power (8/20 μ s)	80	W
T_{OPT}	Operating Temperature	-55~150	$^{\circ}$ C
T_{STG}	Storage Temperature	-55~150	$^{\circ}$ C

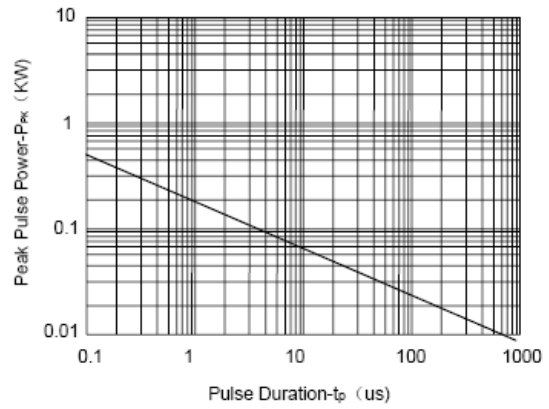
ELECTRICAL CHARACTERISTICS (Tamb=25 $^{\circ}$ C)

Symbol	Parameter	Test Condition	Min	Typ	Max	Units
V_{RWM}	Reverse Working Voltage				5.0	V
V_{BR}	Reverse Breakdown Voltage	$I_T = 1mA$	5.2		8.0	V
I_R	Reverse Leakage Current	$V_{RWM} = 5V$			2.0	μ A
V_C	Clamping Voltage	$I_{PP} = 1A, t_p = 8/20\mu s$			9	V
C_J	Junction Capacitance	$V_R = 0V, f = 1MHz$		4.5	6	pF

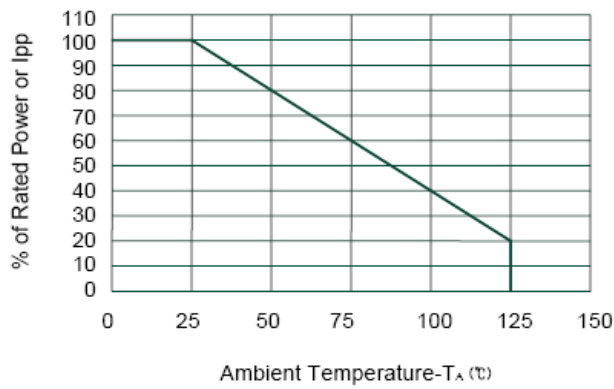
ELECTRICAL CHARACTERISTICS CURVE



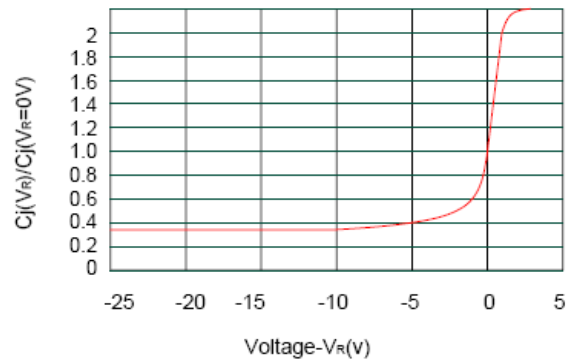
Pulse Waveform



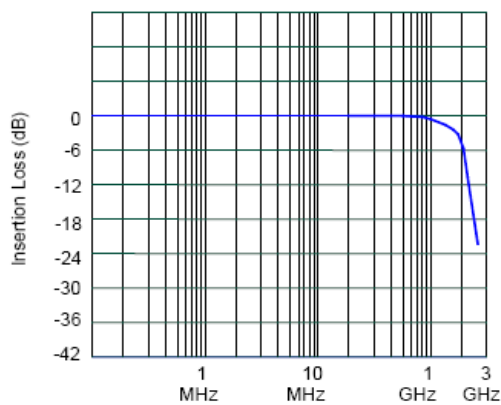
Non-Repetitive Peak Pulse Power vs. Pulse Time



Power Derating Curve

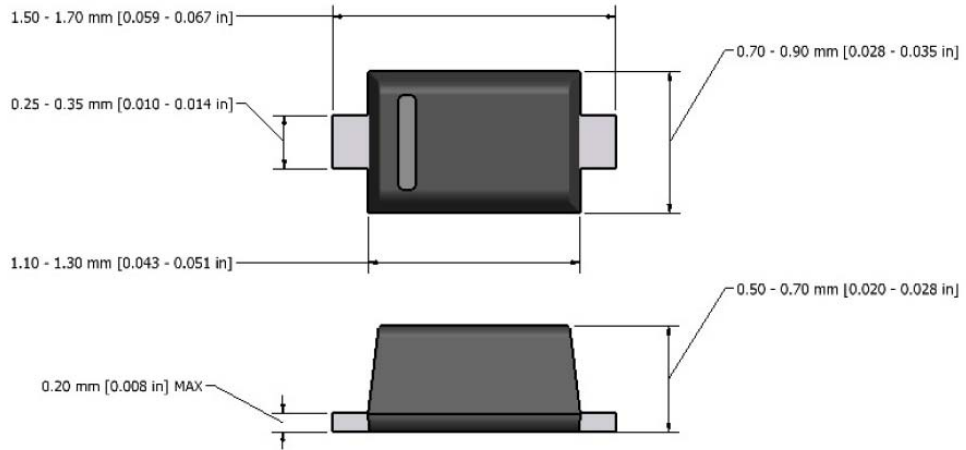


Junction Capacitance vs. Reverse Voltage



Insertion Loss S21

SOD-523 PACKAGE OUTLINE DIMENSIONS



Note: Dimensions are exclusive of Burrs, Mold Flash & Tie Bar extrusions.